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### **EXPLANATION OF REFERENCE**

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100: integrated circuit, 101: light-receiving element, 102: light-emitting element, 103: antenna, 104: substrate, 105: cover material, 110 rectification circuit, 111 power supply circuit, 112: demodulation circuit, 113: logic circuit, 114: memory, 115: memory control circuit, 116: amplifier, 117: amplifier, 201: card body, 202: pixel portion, 203: light-receiving element, 204: light-emitting element, 205: substrate, 206: integrated circuit, 207: display device, 208: antenna, 210: rectification circuit, 211: power supply circuit, 212: demodulation circuit, 213: logic circuit, 214: memory, 215: memory control circuit, 216: amplifier, 217: amplifier, 218: control circuit, 219: signal line driver circuit, 220: scanning line driver circuit, 301: battery, 303: solar battery, 401: integrated circuit, 402: antenna, 403: substrate, 404: adhesive agent, 405: cover material, 406: adhesive agent, 407: IC card, 500: substrate, 501: separation layer, 502:base film, 503: semiconductor film, 504: semiconductor film, 505: semiconductor film, 508: gate insulating film, 509: gate electrode, 510: gate electrode, 513: resist, 514: resist, 515: low concentration impurity region, 518: resist, 519: high concentration impurity region, 520: insulating film, 521: sidewall, 525: resist, 526: high concentration impurity region, 527: high concentration impurity region, 528: high concentration impurity region, 529: n-channel TFT, 530: p-channel TFT, 531: n-channel TFT, 532: n-channel TFT, 533: interlayer insulating film, 534: interlayer insulating film, 535: wiring, 536: wiring, 538: wiring, 540: wiring, 541: wiring, 542: protective layer, 543: groove, 544: adhesive agent, 545: substrate, 546: bank, 547: electroluminescent layer, 548: electrode, 549: light-emitting element, 550: antenna, 551: adhesive agent, 552: cover material, 601: groove, 602: integrated circuit, 603: substrate, 604: separation layer, 605: broken line, 701: n-channel TFT, 702: p-channel TFT, 703: impurity region, 704: channel formation region, 705: semiconductor film, 706: gate insulating film, 707: gate electrode, 707a: conductive film, 708: sidewall, 709: sidewall, 710: LDD (Lightly Doped Drain) region, 711: semiconductor film, 712: impurity region, 713: channel formation region, 721: n-channel TFT, 722: p-channel TFT, 728: sidewall, 741: n-channel TFT, 742: p-channel TFT, 743: impurity region, 744: channel formation region, 745: semiconductor film,

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746: gate insulating film, 747: gate electrode, 748: protective film, 750: LDD (Lightly Doped Drain) region, 751: semiconductor film, 752: impurity region, 753: channel formation region, 1200: bank, 1201: wiring, 1202: wiring, 1203: terminal, 1204: electroluminescent layer, 1205: electrode, 1206: light-emitting element, 1207: adhesive agent, 1208: cover material, 1209: antenna, 1210: substrate, 1211: semiconductor element, 1215: base film, 1301: check, 1302: ID chip, 1303: ID chip, 1304: passport, 1305: ID chip, 1306: gift certificate, 1307: ID chip, 1308: packing material, 1309: boxed meal, 1310: label, 1311: ID chip, 1312: product, 1401: TFT, 1402: semiconductor film, 1403: gate insulating film, 1404: gate electrode, 1405: interlayer insulating film, 1406: interlayer insulating film, 1407: wiring, 1408: antenna, 1409: light-emitting element, 1411: TFT, 1412: semiconductor film, 1413: gate insulating film, 1414: gate electrode, 1418: antenna, 1419: light-emitting element, 1500: photodiode, 1501: interlayer insulating film, 1502: TFT, 1503: interlayer insulating film, 1504: cathode, 1505: photoelectric conversion layer, 1506: anode, 1510: substrate, 1511: photodiode, 1512: light-emitting element, 1513: shielding film, 6001: TFT, 6002: interlayer insulating film, 6003: light-emitting element, 6004: electrode, 6005: electroluminescent layer, 6006: electrode, 6007: interlayer insulating film, 6008: bank, 6009: wiring, 6011: TFT, 6013: light-emitting element, 6014: electrode, 6015: electroluminescent layer, 6016: electrode, 6021: TFT, 6023: light-emitting element, 6024: electrode, 6025: electroluminescent layer, 6026: electrode, 6029: wiring, 6031: TFT, 6033: light-emitting element, 6034: electrode, 6035:electroluminescent layer, 6036: electrode, 6039: wiring, 6041: TFT, 6043: light-emitting element, 6044: electrode, 6045: electroluminescent layer, 6046: electrode, 6051: TFT, 6053: light-emitting element, 6054: electrode, 6055: electroluminescent layer, 6056: electrode, 6059: wiring

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## INTERNATIONALSEARCHREPORT

International application No. PCT/JP2005/003804

### CLASSIFICATION OF SUBJECT MATTER

C. DOCUMENTS CONSIDERED TO BE RELEVANT

Int.CL7G06K19/077, 19/07, H01L27/14, 27/15

According to International Patent Classification (IPC) or to both national classification and IPC

#### FIELDS SEARCHED

Minimum documentation searched (classification system followed by classification symbols) Int.CL7G06K19/077, 19/07, H01L27/14, 27/15

Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched
Published examined utility model applications of Japan 1922-1996
Published unexamined utility model applications of Japan 1971-2005
Registered utility model specifications of Japan 1996-2005
Published registered utility model applications of Japan 1994-2005

Electronic data base consulted during the international search (name of data base and, where practicable, search terms used)

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Y	JP 2001-155134 A (Seiko 2001.06.08, lines 3 to 5, col 6 to line 1, column 7, figs. 4 none)	umn 5, line 27, column	1 - 16
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Further documents are listed in the continuation of Box C.  Special categories of cited documents:  "A" document defining the general state of the art which is not considered to be of particular relevance  "E" earlier application or patent but published on or after the international filing date or understand the principle or theory underlying the invention earlier application or patent but published on or after the international filing date "X" document of particular relevance; the claimed invention cannot be considered novel or cannot be considered to involve an inventive step when the document is taken alone document referring to an oral disclosure, use, exhibition or other means  "P" document referring to an oral disclosure, use, exhibition or other means document published prior to the international filing date but later than the priority date claimed  Date of the actual completion of the international search  31.05.2005			
Name and mailing address of the ISA/JP  Japan Patent Office		Authorized officer Hiroshi MAEDA	5N 2943
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International application No. PCT/JP2005/003804

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